ON Semiconductor

Is Now



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High Current Transistors

PNP Silicon

Features

• Pb-Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	-60	Vdc
Collector - Base Voltage	V _{CBO}	-60	Vdc
Emitter-Base Voltage	V _{EBO}	-4.0	Vdc
Collector Current – Continuous	I _C	-1.0	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

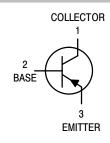
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction–to–Case	$R_{ heta JC}$	83.3	°C/W



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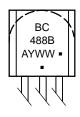
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TO-92 CASE 29 STYLE 17

MARKING DIAGRAM



BC488B = Device Code A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BC488BRL1	TO-92	2000/Tape & Reel
BC488BRL1G	TO-92 (Pb-Free)	2000/Tape & Reel

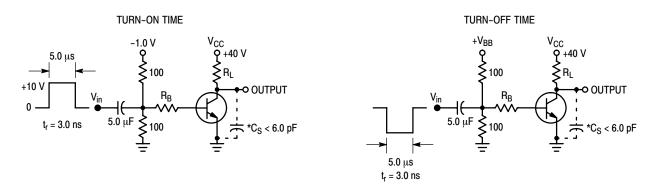
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

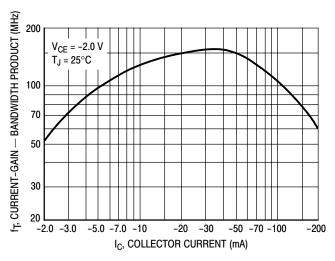
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) (I _C = -10 mAdc, I _B = 0)	V _(BR) CEO	-60	-	_	Vdc
Collector – Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0)	V _(BR) CBO	-60	-	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu Adc$, $I_C = 0$)	V _{(BR)EBO}	-4.0	-	-	Vdc
Collector Cutoff Current (V _{CB} = -40 Vdc, I _E = 0)	Ісво	-	_	-100	nAdc
ON CHARACTERISTICS*	•	•			
DC Current Gain $(I_C = -10 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc})$ $(I_C = -100 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc})$ $(I_C = -1.0 \text{ Adc}, V_{CE} = -5.0 \text{ Vdc})$	h _{FE}	40 160 15	_ 260 _	- 400 -	-
Collector – Emitter Saturation Voltage ($I_C = -500$ mAdc, $I_B = -50$ mAdc) ($I_C = -1.0$ Adc, $I_B = -100$ mAdc)	V _{CE(sat)}	_ _	-0.25 -0.5	-0.5 -	Vdc
Base – Emitter Saturation Voltage ($I_C = -500$ mAdc, $I_B = -50$ mAdc) ($I_C = -1.0$ Adc, $I_B = -100$ mAdc)	V _{BE(sat)}	_ _	-0.9 -1.0	-1.2 -	Vdc
DYNAMIC CHARACTERISTICS	·		•		
Current–Gain – Bandwidth Product (I _C = –50 mAdc, V _{CE} = –2.0 Vdc, f = 100 MHz)	f⊤	_	150	-	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	-	9.0	-	pF
Input Capacitance ($V_{EB} = -0.5 \text{ Vdc}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$)	C _{ib}	-	110	-	pF

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle 2%.



*Total Shunt Capacitance of Test Jig and Connectors For PNP Test Circuits, Reverse All Voltage Polarities

Figure 1. Switching Time Test Circuits



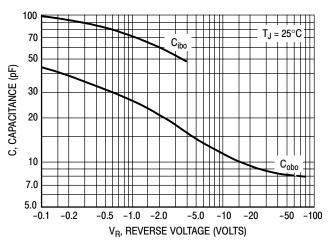


Figure 2. Current-Gain - Bandwidth Product

Figure 3. Capacitance

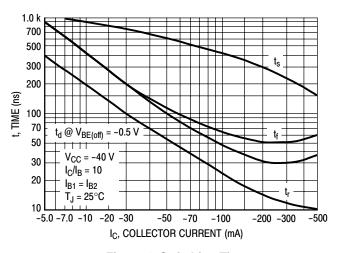


Figure 4. Switching Time

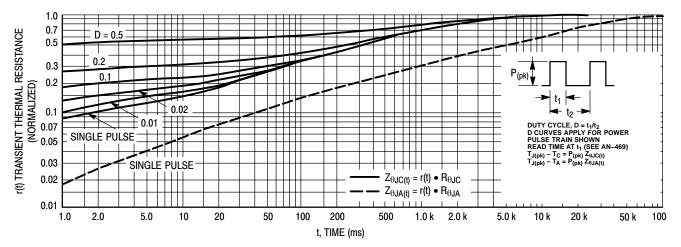
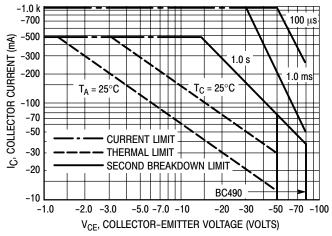


Figure 5. Thermal Response



 V_{CE} , COLLECTOR-EMITTER VOLTAGE (VOLTS) Figure 6. Active Region, Safe Operating Area

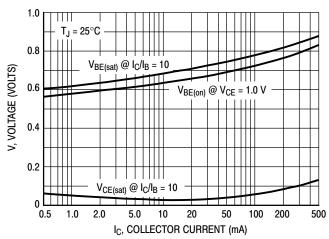


Figure 7. "On" Voltages

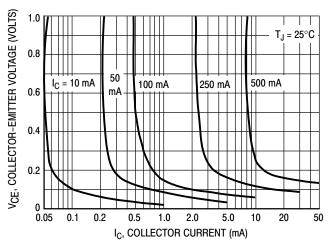


Figure 8. Collector Saturation Region

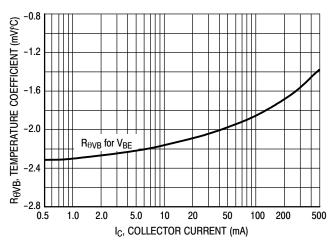


Figure 9. Base-Emitter Temperature Coefficient

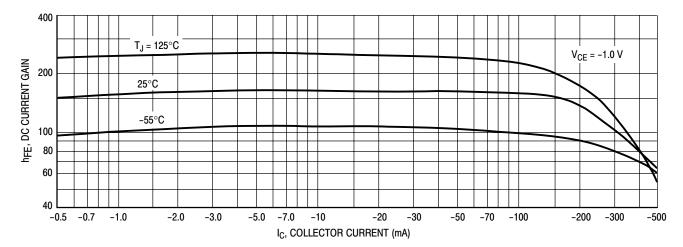
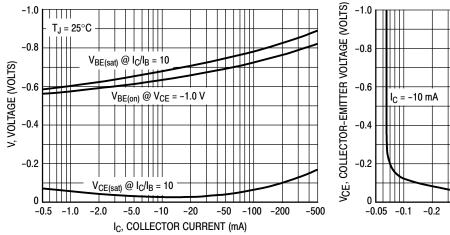


Figure 10. DC Current Gain



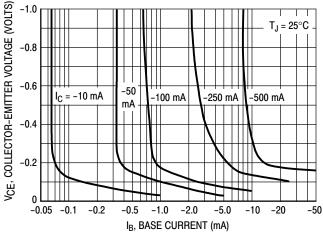


Figure 11. "On" Voltages

Figure 12. Collector Saturation Region

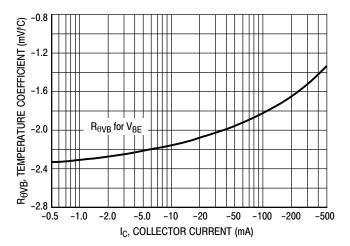
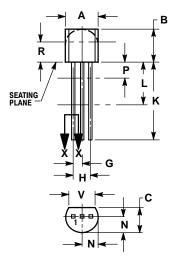


Figure 13. Base-Emitter Temperature Coefficient

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

STYLE 17: PIN 1. COLLECTOR

BASE

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